NSN 5961-01-199-2832

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-199-2832 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.090 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 13.0 breakdown voltage, dc **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 5.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No